Docket: APS 03 - 002

S/N: 10/682,054

In the Specification

Amendments to the Specification:

On page 1, please amend the title of the invention as follows:

<u>DIE PILLAR STRUCTURES AND A METHOD OF THEIR FORMATION</u>

On page 9, please amend the third and fourth paragraphs as

follows:

Fig. 8 illustrates an example die design 100 employing a design of the pillar

structures 34 of the present invention surrounded by the die perimeter 102. As

shown in Fig. 8, the die 100 may include pillar structures/bumps 34 of varying

shapes.

The die perimeter 102 may be used, and provides RF shielding, in Surface

Acoustic Wave (SAW) devices, noise reduction, power current capacity, hermetic

shield and may be used in RF devices, power devices and MEMs for noise isolation

and current capacity.

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